NSN 5961-01-214-8596

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-214-8596 **Inclosure Material:** Plastic **Overall Length:** 12.0 millimeters **Overall Height:** 2.8 millimeters **Overall Width:** 8.5 millimeters **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 300.0 collector to base voltage/static/emitter open and 300.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 100.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector preset **Transfer Ratio:** 40.0 static forward current transfer ratio, common-emitter and 250.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: